

Development of Novel Multicomponent Chalcogenides

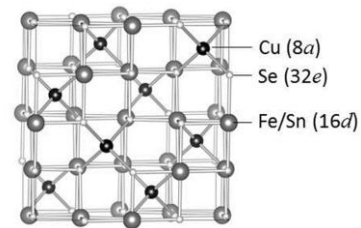
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When we search a light-mass thermoelectric (TE) material with intrinsic low lattice thermal conductivity κ_L , we should seek a material with following structural features; (i) numerous atoms in a unit cell and (ii) complex crystal structure, because they lead to a large phonon-phonon scattering probability. [1] In fact, that materials with the structural feature of (ii) exhibit low κ_L below 1 W/Km. [2] The TE material also demands a high power factor of $PF = S^2/\rho$, where S represents thermopower and ρ denotes electrical. The high PF is sometimes realized in a material with a structure belongs to (iii) a high symmetric crystal system wherein the degeneracy of the band extrema N near the Fermi level tend to be large. [1] Therefore, the light-mass materials having the structural feature of (i)-(iii) is expected to show low κ_L , large PF , and high dimensionless figure of merit $ZT = S^2T/\rho(\kappa_L + \kappa_{el})$, where κ_{el} is electronic contribution of thermal conductivity.

We have been focusing multicomponent chalcogenides with a cubic crystal structure, such as quaternary selenospinel $\text{Cu}_6\text{Fe}_4\text{Sn}_{12}\text{Se}_{32}$. [3,4] The compound has a Fe/Sn disordered 16d crystallographic site which is the cause of structural complexity. As is expected from the structural features, the κ shows low value of 1.2-1.4 W/Km. The ρ decreases and the S increases with increases temperature. Analysis of both properties indicates that the $\text{Cu}_6\text{Fe}_4\text{Sn}_{12}\text{Se}_{32}$ behaves as a variable-range hopping (VRH) conductor below 80 K. The ρ exhibits comparatively low value of 10^{-4} Ωm for a VRH conductor and the S reaches large value of 150 $\mu\text{V/K}$ at 300 K, respectively. The results of ρ , S , and Hall coefficient R_H suggest that the low ρ is attributed to the high hole density about 10^{21} / cm^3 and the large S is achieved by heavy hole band and VRH, respectively. The coexistence of comparatively low ρ and large S might be also attributed to the high N due to high symmetry cubic structure.



Crystal structure of selenospinel

Also a pseudo-ternary sulfide with the crystal structure which fulfill the condition of (i)-(iii) have been studying. The TE properties will be presented.

[1] F. J. DiSalvo, *Science* **285**, 703 (1999).

[2] G. J. Snyder and E. S. Toberer, *Nature mater.* **7**, 105 (2008).

[3] K. Suekuni *et al.*, *J. Appl. Phys.* **109**, 083709 (2011).

[4] K. Suekuni *et al.*, *J. Electron. Mater.*, in print.